

T3-20G

The T3-20G is a high performance mixer featuring LO/RF from 10 MHz to 20 GHz and IF from 1 MHz to 10 GHz. As with all T3 mixers, this mixer offers unparalleled nonlinear performance in terms of IIP3,  $P_{1dB}$ , and spurious performance with a flexible LO drive requirement from +15 dBm to +25 dBm. The T3-20G is offered in connectorized, surface mount, and drop-in style packaging, suitable for any type of system level integration. The T3-20G differs from its sister product the T3-20 in that the T3-20G is built using GaAs diodes instead of Si. For a list of recommended LO driver amps for all mixers and IQ mixers, see <u>here</u>.



#### Features

- Ultra-Broadband RF, LO, and IF
- Compatible with Sine or Square-Wave LO
- Square-Wave LO delivers Industry-Leading Spurious, IP3, and P<sub>1dB</sub> Performance
- Application Note: <u>T3 Mixer Primer</u>

#### Electrical Specifications - Specifications guaranteed from -55 to +100°C, measured in a 50Ω system.

Parameter	LO (GHz)	<b>RF</b> (GHz)	<b>IF</b> (GHz)	Min	Тур	Max	Diode Option LO drive level (dBm)
Conversion Loss (dB)			.001-2		7.5	12.5	
	.01-20	.01-20	.001-5		8.5	14.0	
			.001-10		See IF Plot		
Isolation (dB) LO-RF LO-IF RF-IF	.01-20	.01-20		15 15	See Plots		
Input 1 dB Compression (dBm)	.01-20	.01-20			See Plot		L (+15 to +25)
Input Two-Tone Third Order Intercept Point (dBm)	.01-20	.01-20			See Plots		L (+15 to +25)

#### **Part Number Options**

Please specify diode level and package style by adding to model number.					
Package St	yles		Examp	oles	
Connectorized	<u>S</u>	т	3-20GLS, T3-	20GLES-2	
Microstrip <sup>1,2</sup>	<u>ES</u>	<u>T3-20G</u>	Ŀ	ES	<u>-2</u>
Surface Mount <sup>1,2</sup> (RoHS only)	<u>CTG</u>	(Model)	(Diode Option)	(Package)	(I-Port Configuration)

<sup>1</sup>Connectorized test fixtures available for most microstrip and surface mount packages. Consult factory.

<sup>2</sup>For non-connectorized packages, specify I-port configuration by adding –1 or –2 suffix to model number. Default is –2 configuration when not specified.

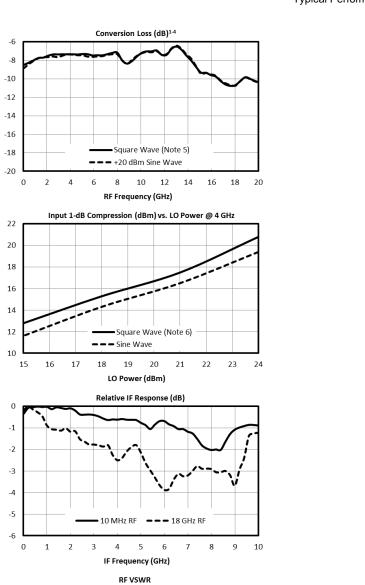


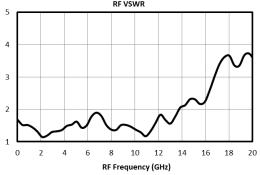
### T3-20G

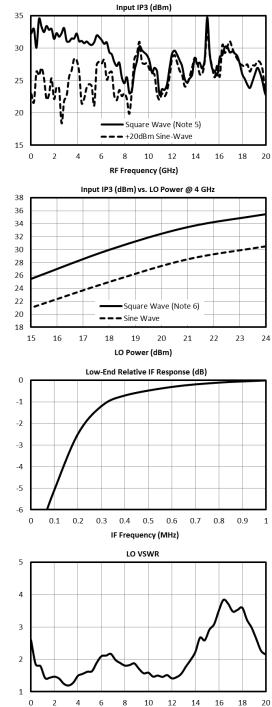
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**Typical Performance** 







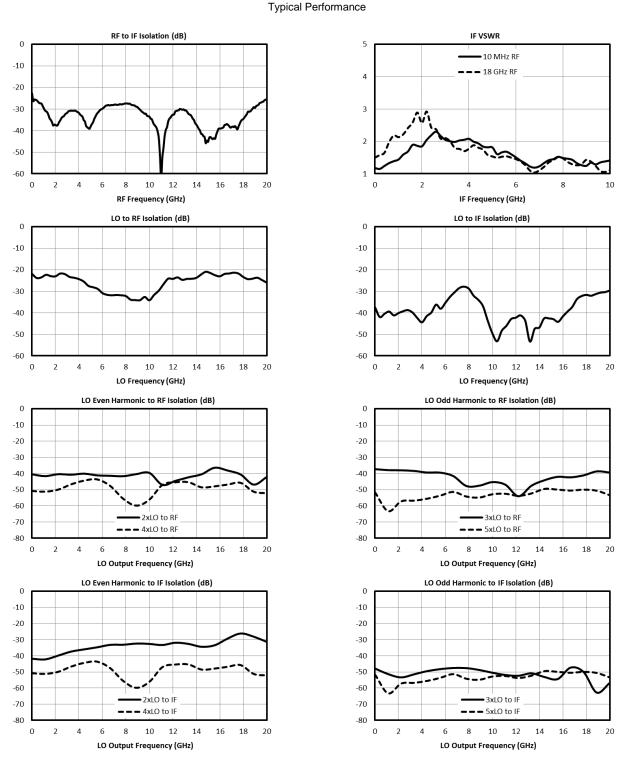
RF Frequency (GHz)



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#### LO/RF 10 MHz to 20 GHz IF 1 MHz to 10 GHz



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LO/RF 10 MHz to 20 GHz IF 1 MHz to 10 GHz

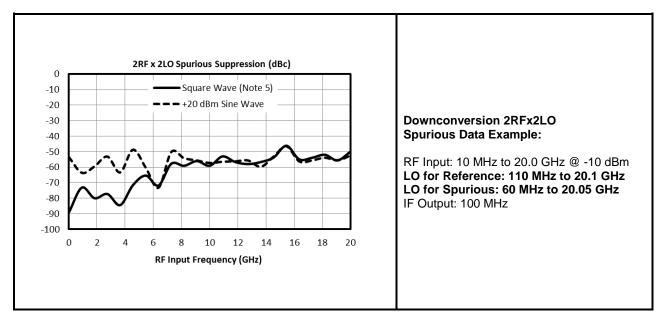
#### **Downconversion Spurious Suppression**

Spurious data is taken by selecting RF and LO frequencies ( $\pm$ mLO $\pm$ nRF) within the 10 MHz to 20 GHz RF/LO bands, which create a 100 MHz IF spurious output. The mixer is swept across the full spurious band and the mean is calculated. The numbers shown in the table below are for a -10 dBm RF input. Spurious suppression is scaled for different RF power levels by (n-1), where "n" is the RF spur order. For example, the 2RFx2LO spur is 63 dBc for a -10 dBm input, so a -20 dBm RF input creates a spur that is (2-1) x (-10 dB) dB lower, or 73 dBc.

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Typical Downconversion S	nurique Si	unnroccion (		ularo Mavo	(Sina Waya)	່ໄດະ
I VUICAI DOWIICOIIVEI SIOII S	purious si	uppression (	ubc). Su	luale wave	Sille wave	

-10 dBm RF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
0xRF		See LO to IF Isolation and LO Harmonic to IF Isolation Plots (Page 3)				
1xRF	20 (23)	Reference	23 (32)	10 (11)	23 (34)	15 (19)
2xRF	66 (64)	69 (65)	63 (56)	67 (63)	67 (55)	72 (60)
3xRF	100 (96)	88 (80)	92 (90)	85 (78)	92 (89)	90 (75)
4xRF	>110	>110	>110	>110	>110	>110
5xRF	>120	>120	>120	>120	>120	>120

A sample downconversion spurious sweep is shown below. An LO which is 100 MHz higher than the RF is used to create a 100 MHz reference IF. A second LO is used to create a 2x2 spurious IF, also at 100 MHz (50 MHz fundamental IF). The difference between these two output levels is the spurious suppression in dBc. The mean value across the full 10 MHz to 20 GHz RF input band is the number shown in the table above.





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#### LO/RF 10 MHz to 20 GHz IF 1 MHz to 10 GHz

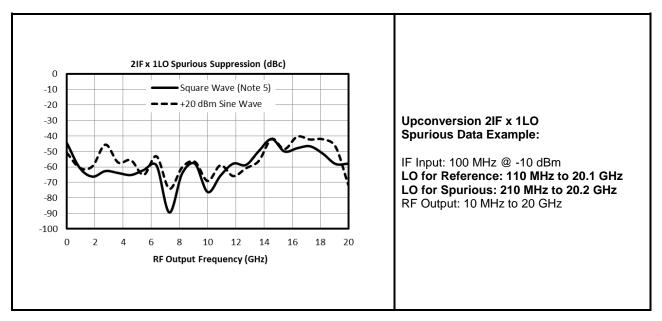
#### **Upconversion Spurious Suppression**

Spurious data is taken by mixing a 100 MHz IF with LO frequencies ( $\pm$ mLO $\pm$ nIF), which creates an RF within the 10 MHz to 20 GHz RF band. The mixer is swept across the full spurious output band and the mean is calculated. The numbers shown in the table below are for a -10 dBm IF input. Spurious suppression is scaled for different IF input power levels by (n-1), where "n" is the IF spur order. For example, the 2IFx1LO spur is typically 59 dBc for a -10 dBm input, so a -20 dBm IF input creates a spur that is (2-1) x (-10 dB) dB lower, or 69 dBc.

Typical Upconversion Spurious Suppression (dBc): Square Wave (Sine Wave) LO	Typical Upconversion	Spurious Suppre	ession (dBc): Square	Wave (Sine Wave) LO <sup>5</sup>
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-10 dBm IF Input	0xLO	1xLO	2xLO	3xLO	4xLO	5xLO
0xIF		See LO to RF Isolation and LO Harmonic to RF Isolation Plots (Page 3)				
1xIF	23 (28)	Reference	27 (30)	10 (11)	27 (37)	15 (20)
2xIF	69 (65)	59 (52)	67 (58)	66 (56)	70 (62)	66 (56)
3xIF	98 (104)	86 (74)	101 (84)	92 (69)	100 (82)	95 (70)
4xIF	>110	>110	>110	>110	>110	>110
5xIF	>120	>120	>120	>120	>120	>120

A sample upconversion spurious sweep is shown below. A 100 MHz reference IF input is used to create an RF output that is 100 MHz below the LO input (LO-IF=RF). A second LO (100 MHz higher) is combined with the same 100 MHz IF input (LO-2xIF=RF) to create the same 10 MHz to 20 GHz RF output band. The difference between these two output levels is the spurious suppression in dBc. The mean value across the full RF output band is the number shown in the table above.

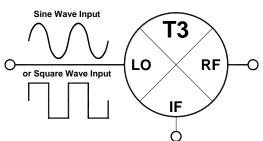




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LO/RF 10 MHz to 20 GHz IF 1 MHz to 10 GHz



Port	Description	DC Interface Schematic
LO	The LO port is DC short to ground and AC matched to 50 Ohms from 10 MHz to 20 GHz. Blocking capacitor is optional.	LO ~
RF	The RF port is DC short to ground and AC matched to 50 Ohms from 10 MHz to 20 GHz. Blocking capacitor is optional.	RF°
IF	The IF port is DC blocked and AC matched to 50 Ohms from 1 MHz to 10 GHz.	IF ⊶⊢ ₂uF

Absolute Maximum Ratings				
Parameter	Maximum Rating			
RF DC Current	1 Amp			
LO DC Current	1 Amp			
RF Power Handling (RF+LO)	+25 dBm (L-Version)			
Operating Temperature	-55°C to +100°C			
Storage Temperature	-65°C to +125°C			
ESD Sensitivity (HBM)	Class 1A			

DATA SHEET NOTES:

1. Mixer Conversion Loss Plot IF frequency is 100 MHz.

2. Mixer Noise Figure typically measures within 0.5 dB of conversion loss for IF frequencies greater than 5 MHz.

Conversion Loss typically degrades less than 0.5 dB for LO drives 2 dB below the lowest and 3 dB above highest nominal LO drive levels.
Conversion Loss typically degrades less than 0.5 dB at +100°C and improves less than 0.5 dB at -55°C.

5. Square Wave Drive created with a chain to two ADM1-0026SM, biased at + 7/-0.25 Volts, with a +10 dBm input. Sine Wave data is taken

5. Square Wave Drive created with a chain to two ADM1-0026SM, biased at + 7/-0.25 Volts, with a +10 dBm input. Sine Wave data is taken with a +20 dBm LO input.

6. Square Wave Drive created with an ADM1-0026SM, biased at + 7/-0.25 Volts, driving an ADM3-0022PA, biased at +7/+15/-0.25/-0.65V.

7. Specifications are subject to change without notice. Contact Marki Microwave for the most recent specifications and data sheets.

8. Catalog mixer circuits are continually improved. Configuration control requires custom mixer model numbers and specifications.



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LO/RF 10 MHz to 20 GHz IF 1 MHz to 10 GHz

**Revision History** 

Revision code	Revision Date	Comment
-	7/7/2020	Pre-release Draft

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